

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	61581	(TFT (thin near5 film near5 transistor))	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 17:27
L2	5626	1 and (anode and cathode)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 17:27
L3	227	2 and (reverse near5 bias near5 volt\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 17:28
L4	41947	(TFT (thin near5 film near5 transistor))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 17:27
L5	297	4 and (anode and cathode)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 17:28
L6	5	5 and (reverse near5 bias near5 volt\$3)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 17:28

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	600252	((light near5 emit\$6 near5 device) LED OLED)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:54
L2	6016	1 and (reverse near5 volt\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:54
L3	2462	2 and cathode	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:55
L4	2028	3 and anode	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:55
L5	1974	4 and (light near5 emitt\$3 ndar5 (diode element))	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:45
L6	1623	4 and (cathode same anode same (light near5 emitt\$3 ndar5 (diode element)))	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:46
L7	756	6 and semiconductor	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:47
L8	38	7 and (avalanche near5 volt\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/14 16:48
L9	192278	((light near5 emit\$6 near5 device) LED OLED)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 16:54
L10	327	9 and (reverse near5 volt\$3)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 16:55
L11	36	10 and cathode	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 16:55
L12	28	11 and anode	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/14 16:55